

 **Insulated Gate Bipolar Transistor**

**Features**

- ▶ Low voltage drop at high currents
- ▶ Industry standard TO-252 (D-Pak) package
- ▶ 700V breakdown voltage rating

**Applications**

- ▶ White goods
- ▶ Small appliances
- ▶ Lighting controls
- ▶ Motor drives
- ▶ Meter readers
- ▶ Small off-line power supplies

**General Description**

The Supertex GN2470 is a 700V, 3.5amp insulated gate bipolar transistor (IGBT) that combines the positive aspects of both BJTs and MOSFETs.

The GN2470 IGBT has lower on-state voltage drop with high blocking voltage capabilities and features many desirable properties including a MOS input gate, low conduction voltage drop at high currents.

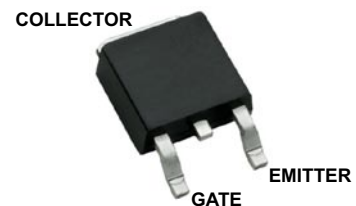
**Ordering Information**

Device	Package Option
	TO-252 (D-PAK)
GN2470	GN2470K4-G

-G indicates that the package is RoHS certified ("Green")

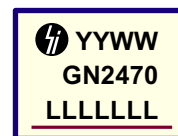


**Pin Configuration**



**TO-252 (D-PAK) (K4)**

**Pin Configuration**



YY = Year Sealed  
 WW = Week Sealed  
 L = Lot Number  
 \_\_\_\_\_ = "Green" Packaging

**TO-252 (D-PAK) (K4)**

**Absolute Maximum Ratings**

Parameter	Value
Collector-to-emitter voltage	700V
Gate-to-emitter voltage	±20V
Operating junction and storage temperature range	-55°C to +150°C
Soldering temperature*	300°C

*Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.*

\* Distance of 1.6mm from case for 10 seconds.

## Thermal Characteristics

Package	$I_C$ (continuous)	$I_C$ (pulsed)	Power Dissipation @ $T_A = 25^\circ\text{C}$	$\theta_{jc}$ ( $^\circ\text{C/W}$ )	$\theta_{ja}$ ( $^\circ\text{C/W}$ )
TO-252	1.0A	3.5A	2.5W	10	60†

**Notes:**

† Mounted on FR4 board, 25mm x 25mm x 1.57mm

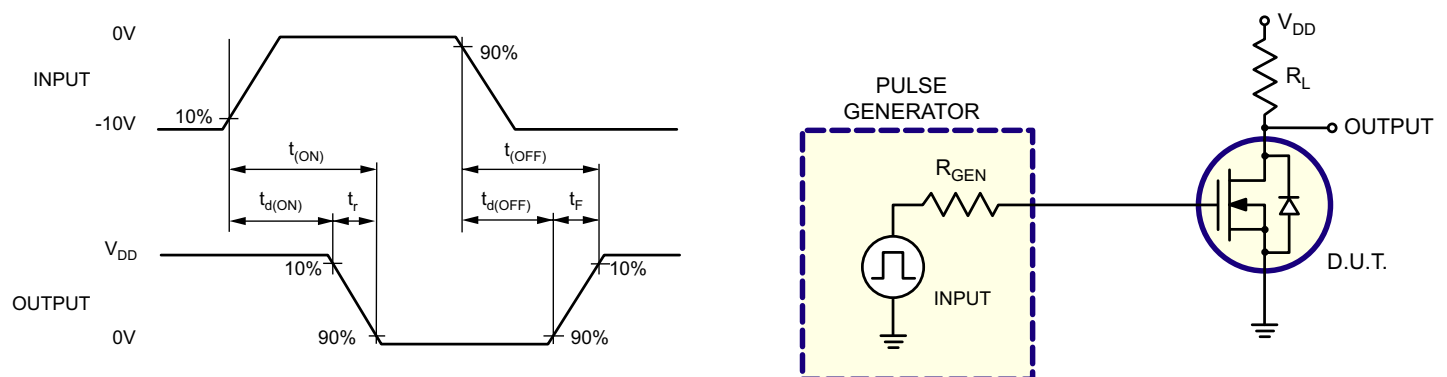
## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Sym	Parameter	Min	Typ	Max	Units	Conditions
$BV_{CES}$	Collector-to-emitter breakdown voltage	700	-	-	V	$V_{GE} = 0V, I_C = 250\mu\text{A}$
$BV_{ECS}$	Emitter-to-collector breakdown voltage	-6.0	-10	-	V	$V_{GE} = 0V, I_C = 1.0\text{mA}$
$V_{GE(th)}$	Gate threshold voltage	1.5	-	3.5	V	$V_{CE} = V_{GE}, I_C = 1.0\text{mA}$
$V_{CE}$	Collector-to-emitter voltage drop	-	4.5	5.0	V	$I_C = 3.0\text{A}, V_{GE} = 13V$
$g_{fe}$	Forward transconductance	0.5	0.8	-	mho	$V_{CE} = 25V, I_C = 2.0\text{A}$
$I_{CES}$	Zero gate voltage collector current	-	-	100	$\mu\text{A}$	$V_{GE} = 0V, V_{CE} = 600V$
$I_{GES}$	Gate-to-emitter leakage current	-	-	$\pm 100$	nA	$V_{GE} = \pm 20V, V_{CE} = 0V$
$I_{C(ON)}$	On-state collector current	3.0	4.0	-	A	$V_{GE} = 10V, V_{CE} = 25V$
$t_{d(ON)}$	Turn-on delay time	-	8.0	15	ns	$V_{CC} = 25V$ $R_{GEN} = 25\Omega$ $R_L = 11\Omega$
$t_r$	Rise time	-	400	600		
$t_{d(OFF)}$	Turn-off delay time	-	20	50		
$t_f$	Fall time	-	7000	12000		
$C_{ISS}$	Input capacitance	-	100	150	pF	$V_{CE} = 25V$ $V_{GE} = 0V$ $f = 1\text{MHz}$
$C_{OSS}$	Output capacitance	-	12	25		
$C_{RSS}$	Reverse transfer capacitance	-	2	5		

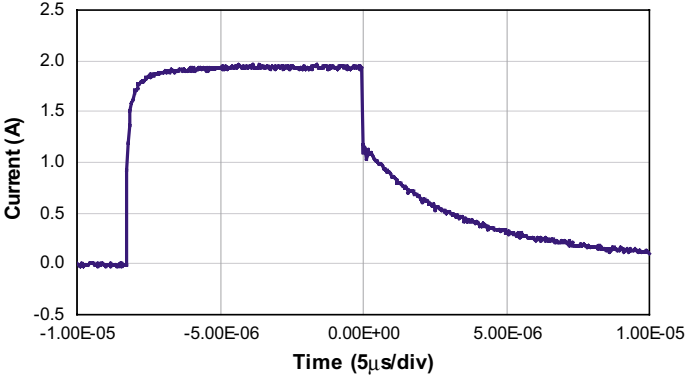
**Notes:**

1. All D.C. parameters 100% tested at  $25^\circ\text{C}$  unless otherwise stated. (Pulse test: 300 $\mu\text{s}$  pulse, 2% duty cycle.)
2. All A.C. parameters sample tested.

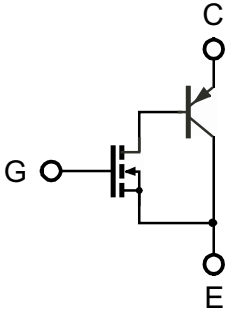
## Switching Waveforms and Test Circuit



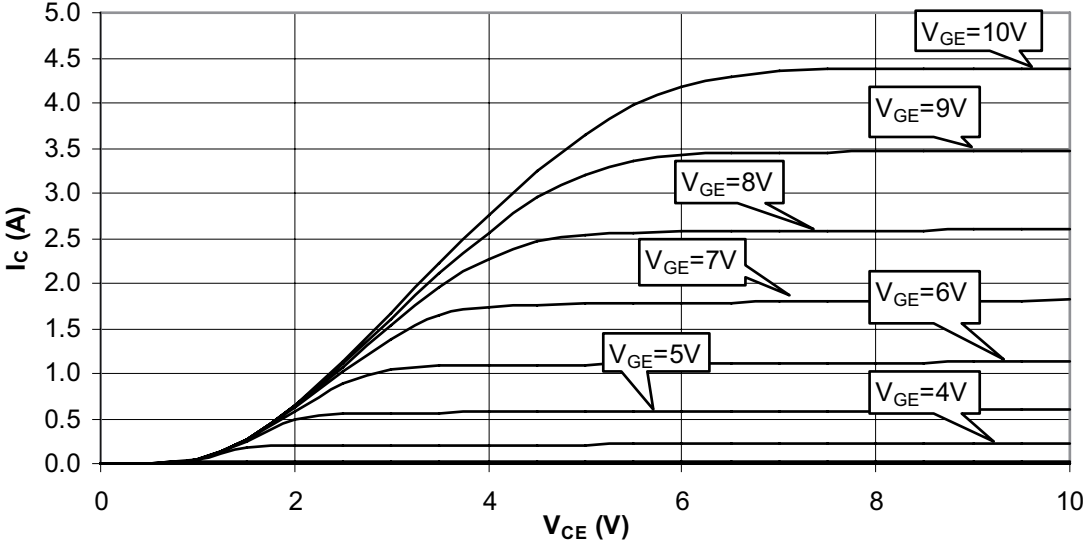
Typical Performance Waveform



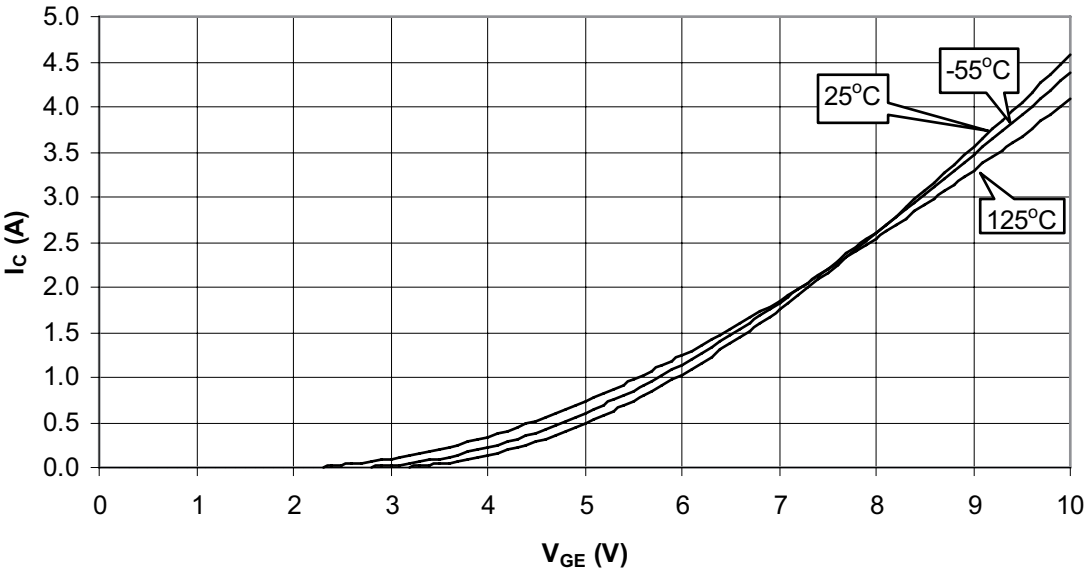
Equivalent Circuit



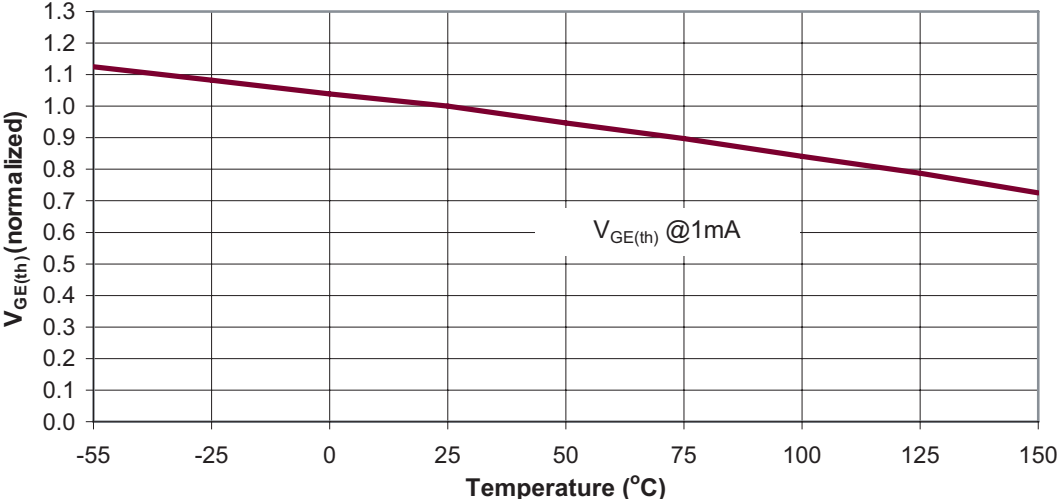
Saturation Characteristics



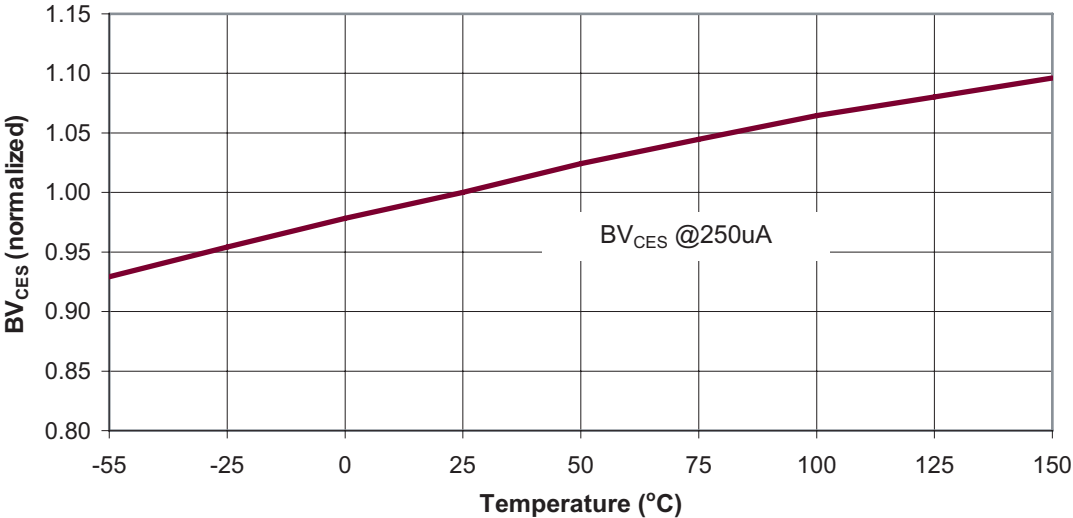
Transfer Characteristics



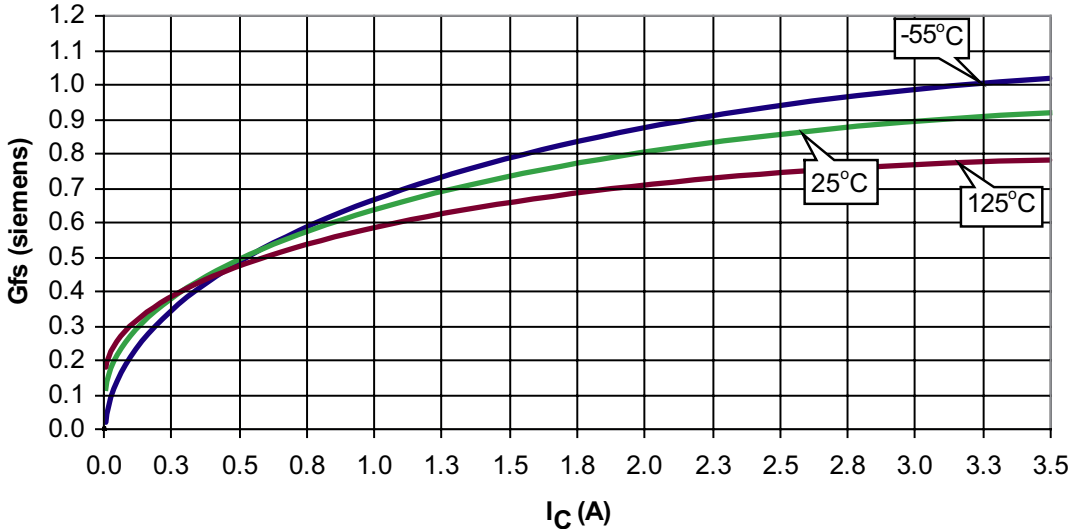
**$V_{GE(th)}$  Variation with Temperature**



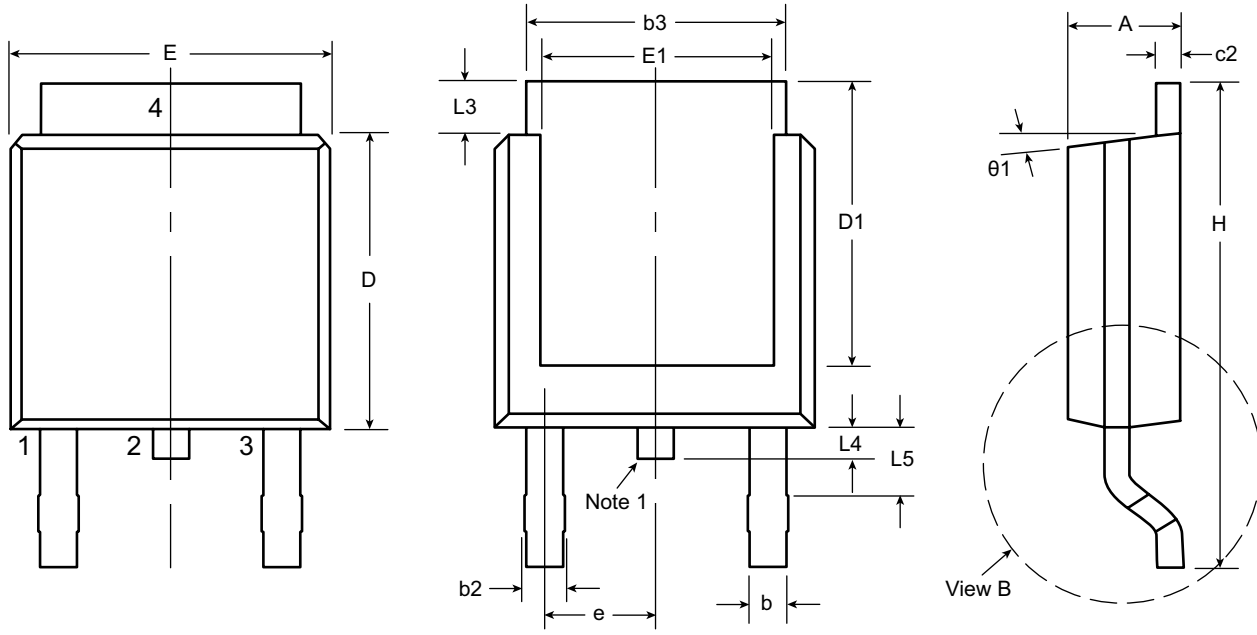
**$BV_{CES}$  Variation with Temperature**



**Transconductance vs. Collector Current**



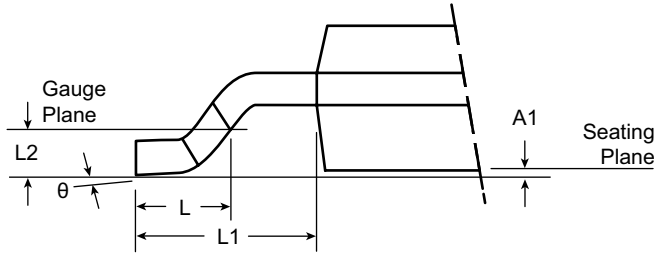
### 3-Lead TO-252 D-PAK Package Outline (K4)



**Front View**

**Rear View**

**Side View**



**View B**

**Note:**  
 1. Although 4 terminal locations are shown, only 3 are functional. Lead number 2 was removed.

Symbol	A	A1	b	b2	b3	c2	D	D1	E	E1	e	H	L	L1	L2	L3	L4	L5	$\theta$	$\theta1$
Dimension (inches)	MIN	.086	.000*	.025	.030	.195	.018	.235	.205	.250	.170	.370	.055	.108 REF	.020 BSC	.035	.025*	.045	0°	0°
	NOM	-	-	-	-	-	-	.240	-	-	.090 BSC	-	.060	-	-	-	-	-	-	-
	MAX	.094	.005	.035	.045	.215	.035	.245	.217*	.265	.182*	.410	.070	-	-	.050	.040	.060	10°	15°

JEDEC Registration TO-252, Variation AA, Issue E, June 2004.  
 \* This dimension is not specified in the original JEDEC drawing. The value listed is for reference only.  
**Drawings not to scale.**  
**Supertex Doc. #: DSPD-3TO252K4, Version D081408.**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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